Amendments to the Claims:

Please cancel claims 1, 4 - 8, 11 - 13, 15 - 17, 21 - 25, 27 and 28 without prejudice or disclaimer of the subject matter therein and add the following new claims.

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

Claims 1 - 28 (canceled)

29. (new) A liquid crystal display device comprising:

a first glass substrate having a thin film transistor and a pixel electrode;

a second glass substrate having a color filter; and

a liquid crystal layer disposed between the first and second substrates;

wherein the thin film transistor includes a silicon film, a gate electrode, and a source electrode which is electrically connected to the pixel electrode;

wherein the pixel electrode includes a reflective electrode forming a reflective region and a light-transmissive electrode forming a transmissive region, and a thickness of the liquid crystal layer of the transmissive region is greater than a thickness of the liquid crystal layer of the reflective region;

wherein between the silicon film and the first substrate and between the pixel electrode and the first substrate, a silicon oxide film and a silicon nitride film are formed, the silicon nitride film being formed between the silicon oxide film and the first substrate;

wherein a film thickness of the silicon nitride film is larger than a film thickness of the silicon oxide film;

wherein the silicon nitride film and the silicon oxide film are configured so as to reduce reflection light from the transmissive region of the liquid crystal display device;

wherein a gate insulation film is formed between the silicon film and the gate electrode;

wherein an interlayer film is arranged close to the gate insulation film and is interposed between the gate insulation film and the pixel electrode; and

wherein the film thickness of the silicon nitride film falls within a range of 126 nm to 165 nm.

30. (new) A liquid crystal display device according to claim 29, wherein the interlayer film includes a first interlayer insulation film and a second interlayer insulation film which is formed between the first interlayer insulation film and the pixel electrode which is made of ITO.

31. (new) A liquid crystal display device according to claim 30, wherein the gate insulation film and the first interlayer insulation film are made of a same material.

32. (new) A liquid crystal display device according to claim 29, wherein a distance from the first substrate to the reflective electrode and a distance from the first substrate to the light-transmissive electrode differ from each other.

33. (new) A liquid crystal display device according to claim 32, wherein an organic film is formed between the reflective electrode and the first substrate.

34. (new) A liquid crystal display device according to claim 33, wherein the pixel electrode is formed on the organic film which is formed on the first substrate, and a common electrode is also formed on the organic film.

35. (new) A liquid crystal display device according to claim 29, wherein the silicon nitride film and the silicon oxide film are configured so as to substantially prevent reflection of external light from the silicon nitride film and the silicon oxide film at the transmissive region of the liquid crystal device in a black display so as to improve contrast.